SURFACE MOUNT SILICON **DUAL N-CHANNEL ENHANCEMENT-MODE MOSFET**



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMLDM7003TG is a dual N-Channel enhancement-mode MOSFET, manufactured by the N-Channel DMOS Process, designed for high speed pulsed amplifier and driver applications. This device offers low r_{DS(ON)}, low V_{GS(th)}, and ESD protection up to 2kV.

MARKING CODE: CTG



• Device is Halogen Free by design

MAXIMUM RATINGS: (TA=25°C)	SYMBOL		UNITS
Drain-Source Voltage	V_{DS}	50	V
Drain-Gate Voltage	V_{DG}	50	V
Gate-Source Voltage	V_{GS}	12	V
Continuous Drain Current	I_{D}	280	mA
Maximum Pulsed Drain Current	I_{DM}	1.5	Α
Power Dissipation (Note 1)	P_{D}	350	mW
Power Dissipation (Note 2)	P_{D}	300	mW
Power Dissipation (Note 3)	P_{D}	150	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	Θ.ΙΔ	357	°C/W

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: (T_A=25°C unless otherwise noted)

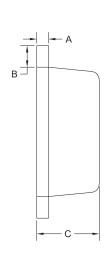
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _{GSSF} , I _{GSSR}	V _{GS} =5.0V			50	nA
IGSSF, IGSSR	V _{GS} =10V			0.5	μΑ
IGSSF, IGSSR	V _{GS} =12V			1.0	μΑ
IDSS	V_{DS} =50V, V_{GS} =0			50	nA
BV _{DSS}	$V_{GS}=0$, $I_D=10\mu A$	50			V
V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	0.7		1.2	V
V _{SD}	V _{GS} =0, I _S =115mA			1.4	V
rDS(ON)	V_{GS} =1.8V, I_D =50mA		1.6	2.3	Ω
rDS(ON)	V_{GS} =2.5V, I_D =50mA		1.3	1.9	Ω
rDS(ON)	V_{GS} =5.0V, I_D =50mA		1.1	1.5	Ω
9FS	V_{DS} =10V, I_D =200mA	200			mS
C _{rss}	V_{DS} =25V, V_{GS} =0, f=1.0MHz			5.0	pF
C _{iss}	V_{DS} =25V, V_{GS} =0, f=1.0MHz			50	pF
Coss	V_{DS} =25V, V_{GS} =0, f=1.0MHz			25	pF
$Q_{g(tot)}$	V_{DS} =25V, V_{GS} =4.5V, I_{D} =100mA		0.764		nC
Q _{gs}	V_{DS} =25V, V_{GS} =4.5V, I_{D} =100mA		0.148		nC
Q_{gd}	V_{DS} =25V, V_{GS} =4.5V, I_{D} =100mA		0.156		nC

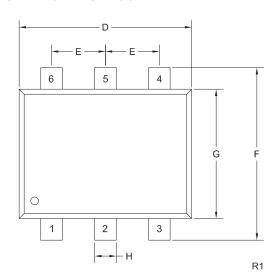
Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of 4.0mm²
(2) FR-4 Epoxy PC Board with copper mounting pad area of 4.0mm²
(3) FR-4 Epoxy PC Board with copper mounting pad area of 1.4mm²

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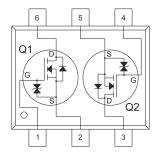


SOT-563 CASE - MECHANICAL OUTLINE





PIN CONFIGURATION



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
Α	0.0027	0.007	0.07	0.18		
В	0.008		0.20			
С	0.017	0.024	0.45	0.60		
D	0.059	0.067	1.50	1.70		
E	0.020		0.50			
F	0.061	0.067	1.55	1.70		
G	0.045	0.049	1.15	1.25		
Н	0.006	0.012	0.15	0.30		

SOT-563 (REV: R1)

LEAD CODE: 1) Gate Q1

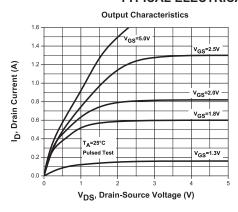
- 2) Source Q1
- 3) Drain Q2
- 4) Gate Q2
- 5) Source Q2
- 6) Drain Q1

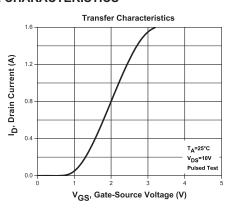
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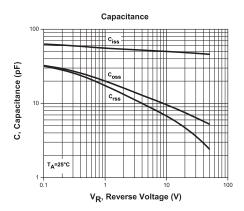
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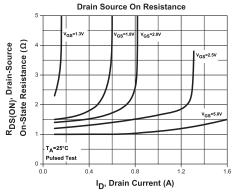


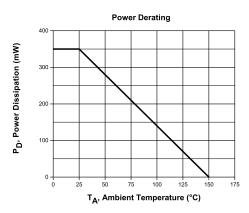
TYPICAL ELECTRICAL CHARACTERISTICS











SURFACE MOUNT SILICON DUAL N-CHANNEL ENHANCEMENT-MODE MOSFET



SERVICES

- · Bonded Inventory
- · Custom Electrical Screening
- Custom Electrical Characteristic Curves
- SPICE Models
- Custom Packaging
- Package Base Options
- Custom Device Development/Multi Discrete Modules (MDM™)
- · Bare Die Available for Hybrid Applications

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